Thyristor Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

2.627 inches

Mounting Facility Quantity:

1

### Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

#### **Features Provided:**

Hermetically sealed case

### **Overall Width Across Flats:**

1.063 inches

Thread Size:

#### 0.500 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

1000.0 repetitive peak off-state voltage and 1000.0 repetitive peak reverse voltage and 1200.0 nonrepetitive peak reverse voltage

### **Current Rating Per Characteristic:**

1.50 milliamperes peak forward surge current absolute

## Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: pnpn

### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

# Unit Of Measure:

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Demilitarization:

No

Fiig:

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